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Team Nexperia



Very low capacitance unidirectional ESD protection diodeRev. 1 — 16 July 2012Product data set

Product data sheet

Product profile 1.

1.1 General description

Very low capacitance unidirectional ElectroStatic Discharge (ESD) protection diode designed to protect one signal line from the damage caused by ESD and other transients. The device is encapsulated in a leadless super small DSN0603-2 (SOD962) Surface-Mounted Device (SMD) package.

1.2 Features and benefits

- ESD protection of one line
- Low diode capacitance C_d = 4 pF
- Super small SMD package

1.3 Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories

1.4 Quick reference data

Table 1. Quick reference data

T_{amb} = 25 °C unless otherwise specified.

- Ultra low leakage current I_{RM} < 1 nA</p>
- ESD protection up to 12 kV
- IEC 61000-4-2; level 4 (ESD)
- Communication systems
- Portable electronics

| unio | 1 | | | | | |
|------------------|--------------------------|------------------------|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _{RWM} | reverse standoff voltage | | - | - | 5 | V |
| C _d | diode capacitance | $f = 1 MHz; V_R = 0 V$ | - | 4 | 5 | pF |



Very low capacitance unidirectional ESD protection diode

2. Pinning information

| Table 2. Pin | Pinning Description | Simplified outline | Graphic symbol |
|-----------------|------------------------|-------------------------|-------------------|
| 1 | cathode | [1] | |
| 2 | anode | 1 2 | 1 2 006aaa 152 |
| | | Transparent top view | |

[1] The marking bar indicates the cathode.

3. Ordering information

| Table 3. Orderii | ng information | | |
|------------------|----------------|--|---------|
| Type number | Package | | |
| | Name | Description | Version |
| PESD5V0V1USF | DSN0603-2 | leadless ultra small package; 2 terminals; body 0.6 \times 0.3 \times 0.3 mm | SOD962 |

4. Marking

| Table 4. | Marking code | | |
|----------|--------------|--------------|--|
| Type num | nber | Marking code | |
| PESD5V0 | W1USF | 3 | |

Very low capacitance unidirectional ESD protection diode

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|----------------------|------------|-----|------|------|
| Tj | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -55 | +150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |

Table 6.ESD maximum ratings

 $T_{amb} = 25$ °C unless otherwise specified.

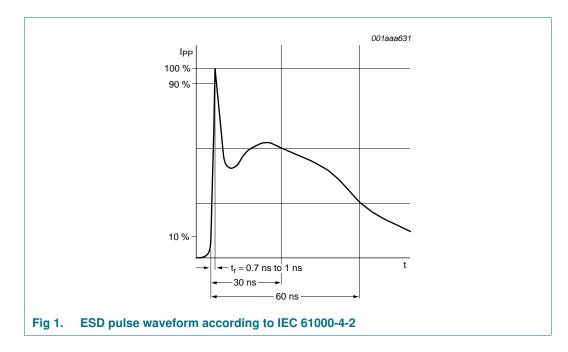
| Symbol | Parameter | Conditions | | Min | Max | Unit |
|---|-----------------------------------|--------------------------------|--------|-----|-----|------|
| V _{ESD} electrostatic discharge voltage | IEC 61000-4-2 (contact discharge) | [1][2] | - | 12 | kV | |
| | discharge voltage | IEC 61000-4-2 (air discharge) | [1][2] | - | 12 | kV |
| | | machine model | [2] | - | 400 | V |
| | | MIL-STD-883 (human body model) | | - | 10 | kV |

[1] Device stressed with ten non-repetitive ESD pulses.

[2] Measured from pin 1 to pin 2.

Table 7. ESD standards compliance

| Standard | Conditions |
|--|------------------|
| IEC 61000-4-2; level 4 (ESD) | > 8 kV (contact) |
| MIL-STD-883; class 3B (human body model) | > 8 kV |



Very low capacitance unidirectional ESD protection diode

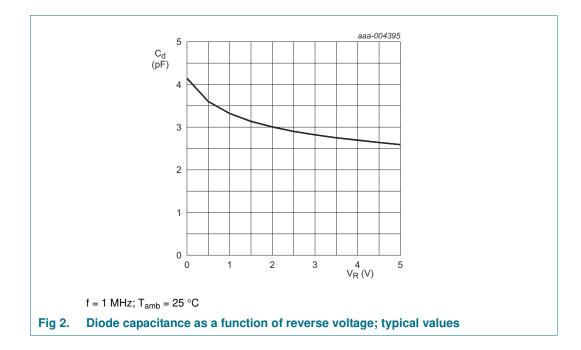
6. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

| $\begin{array}{c c c c c c c c c c c c c c c c c c c $ | anno —• | | | | | | |
|---|------------------|-------------------------|------------------------|--------------|-----|-----|------|
| voltage I_{RM} reverse leakage current $V_{RWM} = 5 V$ -1100nA V_{BR} breakdown voltage $I_R = 1 mA$ 678V C_d diode capacitancef = 1 MHz; $V_R = 0 V$ -45pF | Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
| V_{BR} breakdown voltage $I_R = 1 \text{ mA}$ 678V C_d diode capacitance $f = 1 \text{ MHz}; V_R = 0 \text{ V}$ -45pF | V _{RWM} | | | - | - | 5 | V |
| C_d diode capacitance $f = 1 \text{ MHz}; V_R = 0 \text{ V} - 4 5 \text{ pF}$ | I _{RM} | reverse leakage current | $V_{RWM} = 5 V$ | - | 1 | 100 | nA |
| | V_{BR} | breakdown voltage | I _R = 1 mA | 6 | 7 | 8 | V |
| r_{dyn} dynamic resistance $I_R = 10 A$ [1] - 2 - Ω | C _d | diode capacitance | $f = 1 MHz; V_R = 0 V$ | - | 4 | 5 | pF |
| | r _{dyn} | dynamic resistance | I _R = 10 A | <u>[1]</u> - | 2 | - | Ω |

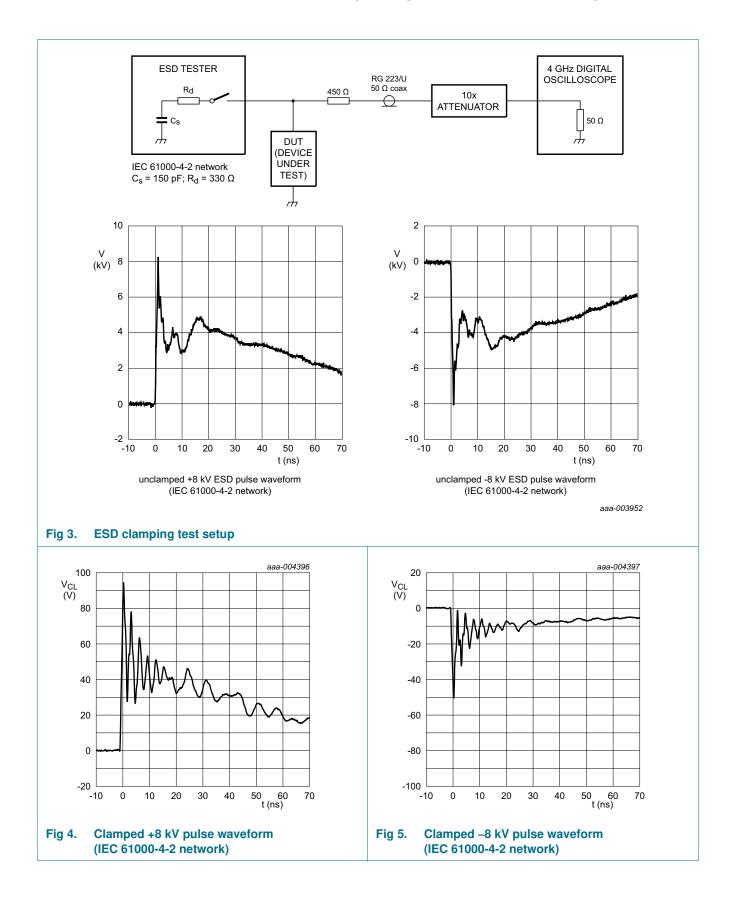
[1] Non-repetitive current pulse, Transmission Line Pulse (TLP) t_p = 100 ns; square pulse; ANS/IESD STM5-1-2008.



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PESD5V0V1USF

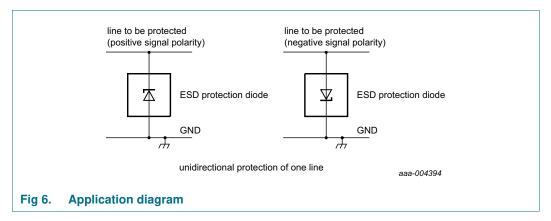
Very low capacitance unidirectional ESD protection diode



Very low capacitance unidirectional ESD protection diode

7. Application information

The device is designed for the protection of one unidirectional data or signal line from surge pulses and ESD damage. The device is suitable on lines where the signal polarities are either positive or negative with respect to ground.



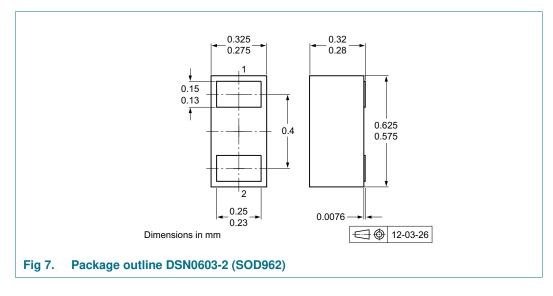
Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the device as close to the input terminal or connector as possible.
- 2. Minimize the path length between the device and the protected line.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Use ground planes whenever possible. For multilayer PCBs, use ground vias.

Very low capacitance unidirectional ESD protection diode

8. Package outline



9. Packing information

Table 9. Packing methods

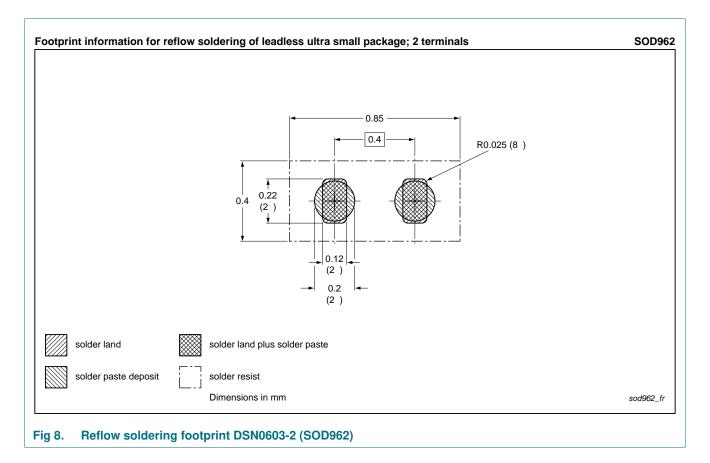
The indicated -xxx are the last three digits of the 12NC ordering code.

| Type number | Package | Description | Packing quantity |
|--------------|-----------------------|--------------------------------|------------------|
| | | | 9000 |
| PESD5V0V1USF | DSN0603-2 (SOD962) | 2 mm pitch, 8 mm tape and reel | -315 |

[1] For further information and the availability of packing methods, see <u>Section 13</u>.

Very low capacitance unidirectional ESD protection diode

10. Soldering



Very low capacitance unidirectional ESD protection diode

11. Revision history

| Table 10. Revision hist | ory | | | |
|-------------------------|--------------|--------------------|---------------|------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| PESD5V0V1USF v.1 | 20120716 | Product data sheet | - | - |

12. Legal information

12.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Date of release: 16 July 2012 Document identifier: PESD5V0V1USF